

 $I_{pn} = 50A$











Representative image only

Features

• Plastic outer case compliant to UL 94-V0

Advantage

- Very good linearity
- Excellent accuracy
- Low temperature drift
- Wide frequency bandwidth
- Optimized response time
- Current overload capability
- No insertion losses

Applications

- Battery supplied applications
- Uninterruptible power supplies (UPS)
- Switched mode power supplies (SMPS)
- AC, DC pulsed in electrical & electronic equipment

Application domain

- Commercial
- Industrial

Standards

- EN 50178
- UL508*

Insulation Characteristics

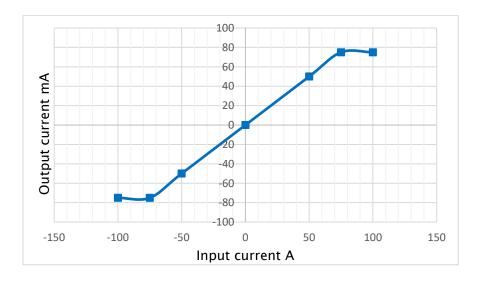
Parameters	Symbol	Value	Units
Dielectric strength between primary and secondary terminals,50Hz, 60 seconds	V _d	2.5	kVrms
Comparative tracking index	CTI	250	V
Insulation resistance at 500 VDC	R _{is}	>100	ΜΩ
Creepage distance		15.00	mm
Clearance distance		11.00	mm



Specifications (Unless otherwise specified temperature is 25°C)

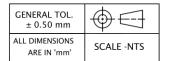
Parameters	Symbol	Condition	Min	Тур	Max	Units
Input current nominal	I _{pn}			50		Arms
Input current measuring range	I _P		-70		+70	Α
Burden resistance	Rb	with ±12V, ±50A at 70°C		70		Ω
		with ±12V, ±70A at 70°C		60		Ω
		with ±12V, ±50A at 85°C		90		Ω
		with ±12V, ±70A at 85°C		70		Ω
		with ±15V, ±50A at 70°C		130		Ω
		with ±15V, ±70A at 70°C		102		Ω
		with ±15V, ±50A at 85°C		150		Ω
		with ±15V, ±70A at 85°C		112		Ω
Secondary winding resistance	Rs			43		Ω
Output current at Ipn	I _{out}			50		mA
Number of secondary turns	Ns			1000		
Theoretical sensitivity	Gth			1		mA/A
Supply voltage	Vs	±5%	±12		±15	V
Current consumption	I _c	$V_s = \pm 15 \text{ V}$		11 + I _{out}		mA
Offset current	Io		-0.2		+0.2	mA
Temperature variation of I_0	I _{ot}	-25 to +85 °C	-0.6		+0.6	mA
		-40 to -25 °C	-1.0		+1.0	
Linearity error	Σ_{l}			<0.15		%
Overall accuracy at Ipn			-0.65		+0.65	%
Reaction time 10% Ipn				<0.5		μs
Response time at 90% of Ipn	t _r	di/dt of 200 A/μs		<1.0		μs
Frequency bandwidth	BW	-1dB, small signal bw	0		200	kHz
di/dt accurately followed	di/dt			>200		A/µs
Ambient operating temperature	T _A		-40		+85	°C
Ambient storage temperature	Ts		-40		+85	°C
Mass	m			25		g

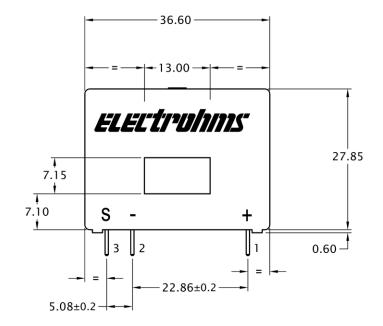
Input & Output Characteristics

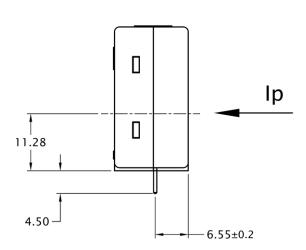


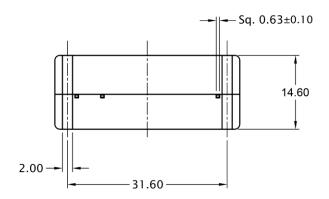


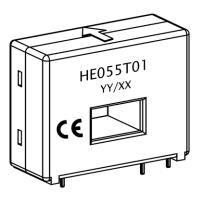
Mechanical dimensions



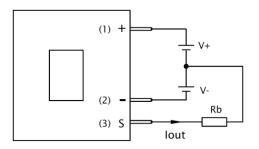








Connection Diagram



Hall Effect Current Sensor HE055T01



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- Sensor mounting: PCB mountable.
- It is recommended to centrally locate the current carrying conductor or completely fill the central opening for optimum performance.
- Output is positive when current (Ip) flows in the direction of arrow.
- * Designed to meet UL508.
- Ensure proper connection of power supply to avoid damage to the sensor.

Safety



• This Sensor must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



- Caution, risk of electrical shock
- When operating the Sensor, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).
- Ignoring this warning can lead to injury and/or cause serious damage.
- A protective housing or additional shield could be used.
- Over currents (»I_{PN}) can cause an additional voltage offset due to magnetic remanence.
- The temperature of the primary conductor shall not exceed 100 °C.
- This Sensors must be used in electrical or electronic systems as per the applicable standards.
- Protect non-isolated high-voltage current carrying parts against direct contact (e.g. with a protective housing)
- When installing the sensor, ensure that the safe separation (between primary circuit and secondary circuit) is maintained over the whole circuits and their connections.

General information:

Electrohms reserves the right to make modifications on products for improvements without prior notice.